

On the Einstein model for EXAFS parallel and perpendicular mean-square relative displacements

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The correlated Einstein model for EXAFS parallel and perpendicular mean-square relative displacements (MSRDs) is discussed. By means of dynamical simulations on different crystalline structures, the error owing to the Einstein-fit model on the EXAFS MSRDs is estimated as a function of the standard deviation of the density of vibrational states. This error should be taken into account to improve the accuracy of the MSRDs.

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1. Introduction

Extended X-ray absorption fine structure (EXAFS) is known as a powerful probe for investigating disordered systems and, thanks to accurate temperature-dependent measurements, for obtaining original information on the local dynamics of crystals, such as the parallel and perpendicular mean-square relative displacements (Brewer *et al.*, 1997; Fornasini *et al.*, 2004). Indicating by $\bar{\mathbf{u}}_0$ and $\bar{\mathbf{u}}_1$ the thermal displacement of the absorber and backscatterer atoms of EXAFS, respectively, the parallel mean-square relative displacement (MSRD_∥) is defined as

$$\text{MSRD}_{\parallel} = \langle |(\bar{\mathbf{u}}_1 - \bar{\mathbf{u}}_0) \cdot \hat{\mathbf{R}}|^2 \rangle, \quad (1)$$

and the perpendicular mean-square relative displacement (MSRD_⊥) as

$$\text{MSRD}_{\perp} = \langle |\bar{\mathbf{u}}_1 - \bar{\mathbf{u}}_0|^2 \rangle - \langle |(\bar{\mathbf{u}}_1 - \bar{\mathbf{u}}_0) \cdot \hat{\mathbf{R}}|^2 \rangle, \quad (2)$$

where $\hat{\mathbf{R}}$ is the unit vector of the equilibrium distance between the two atoms. The EXAFS Debye–Waller factor directly gives information on MSRD_∥ (Beni & Platzman, 1976). The difference between the interatomic distance $\langle r \rangle = \langle |\bar{\mathbf{R}} + \bar{\mathbf{u}}_1 - \bar{\mathbf{u}}_0| \rangle$ probed by EXAFS and the crystallographic distance $R = \langle |\bar{\mathbf{R}} + \bar{\mathbf{u}}_1 - \bar{\mathbf{u}}_0| \rangle$ between average positions allows measurement of the temperature dependence of MSRD_⊥ (Dalba *et al.*, 1999).

The EXAFS MSRDs represent a test bench for lattice dynamical theories; their comparison with the absolute mean-square displacements (MSDs) obtained from X-ray diffraction allows evaluation of the correlation of atomic motions, which plays a key role in the study of some physical phenomena such as phase transitions and negative thermal expansion (Sanson *et al.*, 2006).

To find accurate values of MSRD_∥ and MSRD_⊥ by EXAFS, an accurate knowledge of the EXAFS scattering amplitudes, phase shifts and inelastic terms is required (Teo, 1986). These parameters can be determined by theoretical calculations, for

example using *FEFF8* code (Ankudinov *et al.*, 1998). However, the uncertainties on these calculations affect the accuracy on the absolute value of MSRD_∥ and MSRD_⊥. An alternative procedure consists of a separate analysis of phase and amplitude of the filtered EXAFS signal *via* the ratio method (Bunker, 1983; Tranquada & Ingalls, 1983) taking the lowest-temperature spectra as reference for backscattering amplitudes, phase shifts and inelastic terms. However, only the relative differences $\delta\text{MSRD}_{\parallel}(T) = \text{MSRD}_{\parallel}(T) - \text{MSRD}_{\parallel}(T_0)$ and $\delta\text{MSRD}_{\perp}(T) = \text{MSRD}_{\perp}(T) - \text{MSRD}_{\perp}(T_0)$ with respect to the reference temperature T_0 can be obtained from this second procedure. In both procedures it is customary to fit the temperature dependence of $\delta\text{MSRD}_{\parallel}(T)$ and $\delta\text{MSRD}_{\perp}(T)$ to a correlated Einstein model in order to obtain with reasonable accuracy the absolute value of MSRD_∥(T) and MSRD_⊥(T) (Dalba & Fornasini, 1997).

In the correlated Einstein model, which consists of substituting the phonon density of states $\rho(\nu)$ with a delta function centred at ν_E , one obtains the following expressions for MSRD_∥(T) and MSRD_⊥(T) (Sevillano *et al.*, 1979; Vaccari & Fornasini, 2006),

$$\text{MSRD}_{\parallel}^{\text{ein}}(T) = h/(8\pi^2 \mu \nu_{\parallel}) \coth(h\nu_{\parallel}/2k_B T), \quad (3)$$

$$\text{MSRD}_{\perp}^{\text{ein}}(T) = h/(4\pi^2 \mu \nu_{\perp}) \coth(h\nu_{\perp}/2k_B T). \quad (4)$$

To obtain the absolute values of MSRD_∥(T) and MSRD_⊥(T) from the experimental temperature-dependence of $\delta\text{MSRD}_{\parallel}(T)$ and $\delta\text{MSRD}_{\perp}(T)$, one uses the following fit expressions,

$$\delta\text{MSRD}_{\parallel}(T) = h/(8\pi^2 \mu \nu_{\parallel}) \coth(h\nu_{\parallel}/2k_B T) - a_{\parallel}, \quad (5)$$

$$\delta\text{MSRD}_{\perp}(T) = h/(4\pi^2 \mu \nu_{\perp}) \coth(h\nu_{\perp}/2k_B T) - a_{\perp}, \quad (6)$$

where a_{\parallel} , a_{\perp} and the Einstein frequencies ν_{\parallel} , ν_{\perp} are the only fitting parameters. The absolute values of MSRD_∥(T) and MSRD_⊥(T) are obtained, respectively, by shift

$$\text{MSRD}_{\parallel}(T) = \delta\text{MSRD}_{\parallel}(T) + a_{\parallel}, \quad (7)$$

$$\text{MSRD}_{\perp}(T) = \delta\text{MSRD}_{\perp}(T) + a_{\perp}. \quad (8)$$

Although the Einstein model is based on a strong assumption (phonon spectrum approximated to a single frequency), it is a matter of experience that the temperature dependence of the experimental MSRDS can be reasonably fitted by this model. However, the error deriving from this procedure has never been estimated. This is the aim of this work: to estimate, for the first time, the error on the absolute value of the EXAFS MSRDS owing to the use of the Einstein-fit model.

The paper is organized as follows: in §2 the procedure of estimating the EXAFS MSRDS error is briefly described; in §3 the results are reported and discussed; a remark on the connection between Einstein-model and crystal dynamics is made in §4; §5 is dedicated to conclusions.

2. Procedure

As a first step, the temperature dependences of $\text{MSRD}_{\parallel}(T)$ and $\text{MSRD}_{\perp}(T)$ have been calculated (between 0 and 1000 K) in different crystals by means of dynamical simulations. The dynamical calculations have been performed within the Born–Von Karman approximation (Maradudin *et al.*, 1971) on the following crystalline structures: face-centered cubic, diamond structure, wurtzite and cuprite (one, two, four and six atoms in the elementary cell, respectively) with arbitrary force constants and atomic masses, in all 27 crystals. The parallel and the perpendicular $\text{MSRD}(T)$ are calculated in terms of eigenfrequencies $\nu(\lambda, \vec{q})$ and eigenvectors $\vec{w}_i(\lambda, \vec{q})$ of the dynamical matrix (for more details see Maradudin *et al.*, 1971; Vaccari & Fornasini, 2006) as

$$\begin{aligned} \text{MSRD}_{\parallel}(T) = & (1/N) \sum_{\lambda, \vec{q}} h/[8\pi^2 \nu(\lambda, \vec{q})] \coth[h\nu(\lambda, \vec{q})/2k_B T] \\ & \times |[\vec{w}_2(\lambda, \vec{q}) \exp(i\vec{q} \cdot \vec{R})/M_1^{1/2} \\ & - \vec{w}_1(\lambda, \vec{q})/M_0^{1/2}] \cdot \hat{R}|^2, \end{aligned} \quad (9)$$

and

$$\begin{aligned} \text{MSRD}_{\perp}(T) = & (1/N) \sum_{\lambda, \vec{q}} h/[8\pi^2 \nu(\lambda, \vec{q})] \coth[h\nu(\lambda, \vec{q})/2k_B T] \\ & \times |\vec{w}_2(\lambda, \vec{q}) \exp(i\vec{q} \cdot \vec{R})/M_1^{1/2} \\ & - \vec{w}_1(\lambda, \vec{q})/M_0^{1/2}|^2 - \text{MSRD}_{\parallel}(T). \end{aligned} \quad (10)$$

As a second step, the relative differences with respect to 0 K, *i.e.* $\delta\text{MSRD}_{\parallel}(T) = \text{MSRD}_{\parallel}(T) - \text{MSRD}_{\parallel}(0)$ and $\delta\text{MSRD}_{\perp}(T) = \text{MSRD}_{\perp}(T) - \text{MSRD}_{\perp}(0)$, have been fitted with the correlated Einstein model in agreement with equations (5) and (6), respectively. As a result, the fitting parameters a_{\parallel} and a_{\perp} (as well as ν_{\parallel} and ν_{\perp}) have been obtained for each crystal.

For the third step, if the Einstein-fit error is zero, then $a_{\parallel} = \text{MSRD}_{\parallel}(0)$ and $a_{\perp} = \text{MSRD}_{\perp}(0)$, and so $\delta\text{MSRD}_{\parallel}(T) + a_{\parallel}$ and $\delta\text{MSRD}_{\perp}(T) + a_{\perp}$ must give $\text{MSRD}_{\parallel}(T)$ and $\text{MSRD}_{\perp}(T)$, respectively. As a consequence, the percentage errors on MSRD_{\parallel} and MSRD_{\perp} at temperature T have been estimated, respectively, as

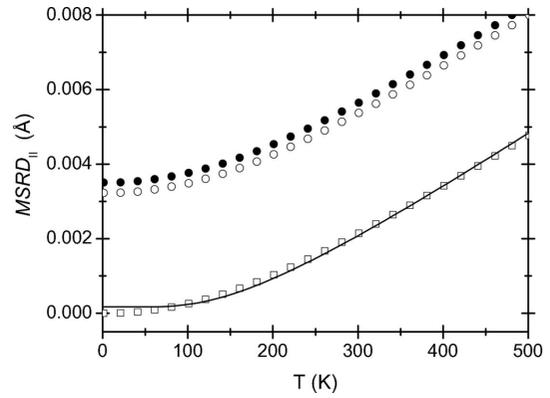


Figure 1

Example of the Einstein fit on the parallel mean-square relative displacement: $\text{MSRD}_{\parallel}(T)$ calculated by dynamical simulation (open circles), relative differences $\delta\text{MSRD}_{\parallel}(T)$ with respect to 0 K (open squares) and corresponding Einstein fit (line). The resulting $\text{MSRD}_{\parallel}(T)$ from the Einstein fit (full circles) is shifted with respect to the correct $\text{MSRD}_{\parallel}(T)$ (open circles).

$$\% \text{Err}_{\parallel}(T) = \frac{a_{\parallel} - \text{MSRD}_{\parallel}(0)}{\text{MSRD}_{\parallel}(T)} \times 100, \quad (11)$$

$$\% \text{Err}_{\perp}(T) = \frac{a_{\perp} - \text{MSRD}_{\perp}(0)}{\text{MSRD}_{\perp}(T)} \times 100. \quad (12)$$

Fig. 1 shows an example of calculated $\text{MSRD}_{\parallel}(T)$, the relative difference $\delta\text{MSRD}_{\parallel}(T)$ with respect to 0 K, and the corresponding Einstein fit by equation (5). The resulting shift between $\text{MSRD}_{\parallel}(T)$ and $\delta\text{MSRD}_{\parallel}(T) + a_{\parallel}$ (open and full circles, respectively) is the error on the absolute $\text{MSRD}_{\parallel}(T)$ owing to the Einstein fit.

It can be expected that the error owing to the Einstein fit increases with an increase in the standard deviation of the density of vibrational states (DOS) of the crystal. In a ‘perfect Einstein crystal’, where DOS is a δ function and the DOS standard deviation is zero, the Einstein-fit error is zero. As a consequence, in §3, for each crystal the Einstein-fit error has been plotted against the DOS standard deviation. Fig. 2 shows three examples of the calculated DOS with different standard deviations.

3. Results and discussion

According to equations (5)–(6) and (9)–(12), the percentage errors on $\text{MSRD}_{\parallel}(T)$ and $\text{MSRD}_{\perp}(T)$ at 0, 300 and 600 K have been calculated and plotted against the DOS standard deviation of the crystal (Figs. 3 and 4). The Einstein fit has been performed over a typical experimental range, between 0 and 500 K. To first approximation, the correlation between the Einstein error and the DOS standard deviation is independent of the crystal structure.

From Figs. 3 and 4 it can be observed that (i) the Einstein fit gives an overestimation of both $\text{MSRD}_{\parallel}(T)$ and $\text{MSRD}_{\perp}(T)$ ($\% \text{Err}_{\parallel}$ and $\% \text{Err}_{\perp}$ are always greater than zero); (ii) the error on $\text{MSRD}_{\perp}(T)$ is about two times the error on

$MSRD_{\parallel}(T)$ ($\%Err_{\perp} \simeq 2\%Err_{\parallel}$); (iii) on average, the error is within 5% on $MSRD_{\parallel}(T)$ and within 10% on $MSRD_{\perp}(T)$, at least if 0–500 K is considered as the fitting interval.

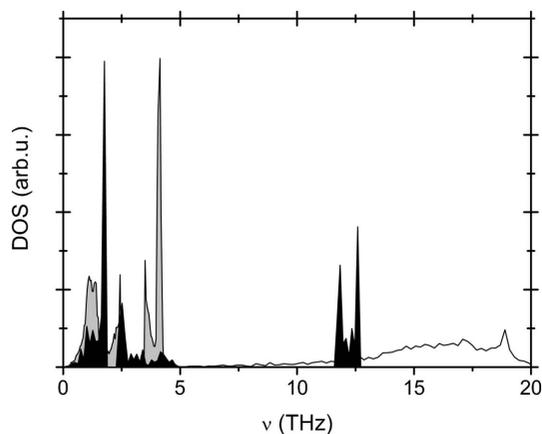


Figure 2
Examples of calculated phonon DOS with different standard deviations: 1.3 THz (gray), 3.0 THz (white) and 4.8 THz (black).

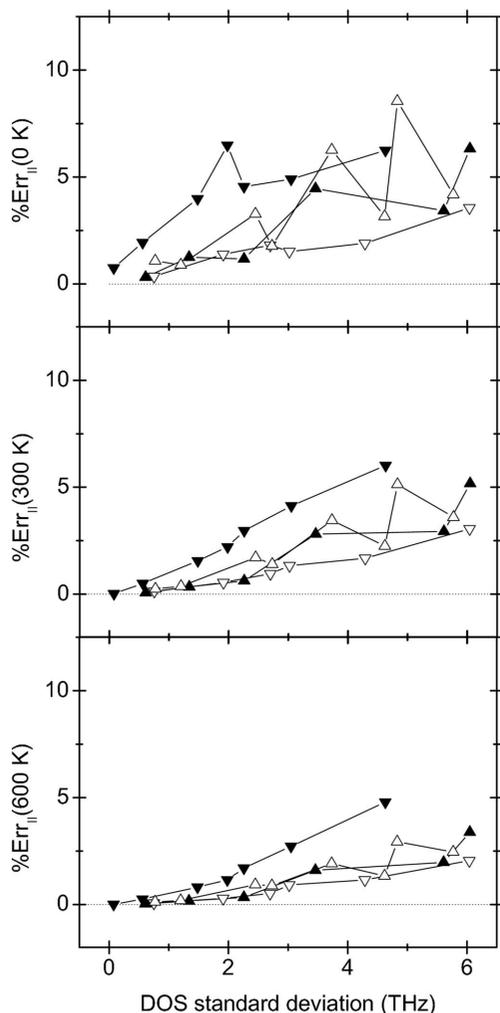


Figure 3
Percentage error given by the Einstein fit on the absolute $MSRD_{\parallel}(T)$ at 0, 300 and 600 K, calculated in different crystalline structures: face-centered cubic (full-down triangles), diamond (open-down triangles), wurtzite (full-up triangles) and cuprite (open-up triangles). Lines are a guide for the eyes.

It is obvious that the error owing to the Einstein fit depends on the fitting interval. Since at high temperatures equations (5)–(6) are approximated by a classical linear behaviour, problems are mainly expected at low temperatures. Fig. 5 reports the percentage error in the diamond structure obtained with four different fitting intervals: 0–300 K, 0–500 K, 0–1000 K and 200–1000 K. The error is reduced when the high-temperature range prevails against the low-temperature range in the fitting procedure. Analogous results have been obtained for the other three crystalline structures.

From this result one finds that it is more convenient to fit the experimental $\delta MSRD_{\parallel}(T)$ and $\delta MSRD_{\perp}(T)$ neglecting the low-temperature intervals. However, this is true only in ideal situations. In real situations, where $\delta MSRD_{\parallel}(T)$ and $\delta MSRD_{\perp}(T)$ are affected by experimental uncertainties, it is probably more convenient to fit the whole available temperature range in order to maximize the experimental information. In any case, the high-temperature ranges reduce the Einstein error on the absolute MSRDs.

Only recently expression (4) for perpendicular MSRD has been derived by Vaccari & Fornasini (2006). In previous works (for example, Dalba *et al.*, 1999; Fornasini *et al.*, 2004) the

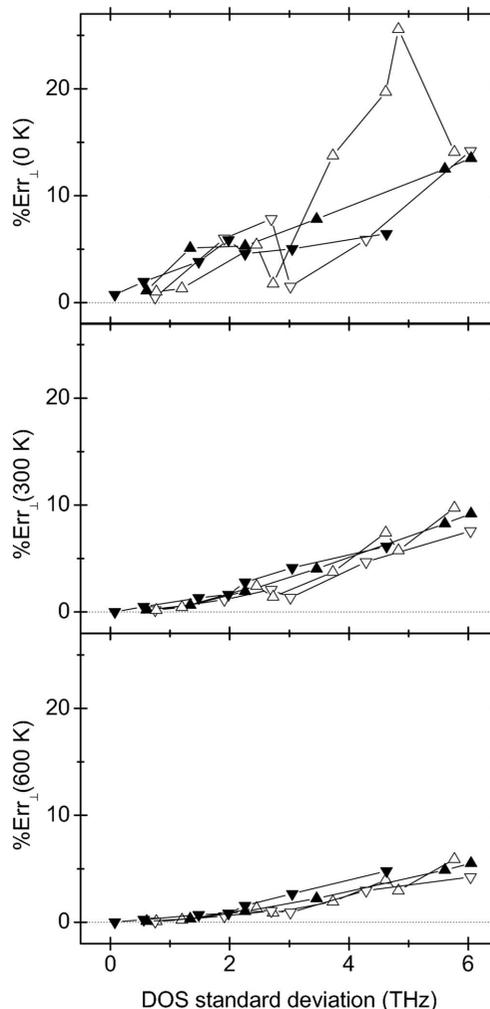
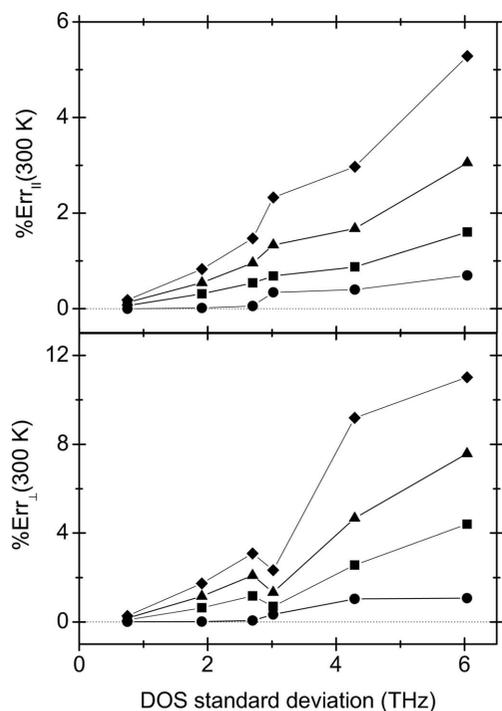
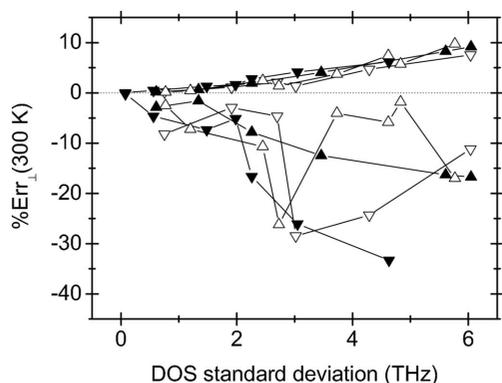


Figure 4
Percentage error given by the Einstein fit on the absolute $MSRD_{\perp}(T)$ at 0, 300 and 600 K. Symbols are the same as in Fig. 3.


Figure 5

Percentage error given by the Einstein fit on the absolute $\text{MSRD}_{\parallel}(T)$ and $\text{MSRD}_{\perp}(T)$ (top and bottom panel, respectively) in diamond structure at 300 K for different fitting intervals: 0–300 K (diamonds), 0–500 K (triangles), 0–1000 K (squares) and 200–1000 K (circles). The error reduces when the high temperatures prevail in the fitting range.

absolute $\text{MSRD}_{\perp}(T)$ was estimated from the correlated Einstein model for parallel MSRD, *i.e.* using equation (5) instead of equation (6). The use of equation (5), which differs by a factor of two from equation (6), is equivalent to inserting an incorrect value of the reduced mass μ (twice the real value) in the fitting procedure of $\text{MSRD}_{\perp}(T)$. I have estimated the error owing to the utilization of equation (5) instead of equation (6): as shown in Fig. 6, equation (5) gives an underestimation ($\% \text{Err}_{\perp} < 0$) on the absolute value of $\text{MSRD}_{\perp}(T)$, and the error is about twice that resulting from equation (6). As a consequence, equation (6) is fundamental


Figure 6

Percentage error on the absolute $\text{MSRD}_{\perp}(T)$ at 300 K: with $\delta \text{MSRD}_{\perp}(T)$ fitted by equation (5) (negative values) and by equation (6) (positive values). The fit was made between 0 and 500 K. Symbols are the same as in Fig. 3.

in the fitting of perpendicular MSRD. For the first time it has been used by Vaccari *et al.* (2007) on cuprous chloride.

In the practical EXAFS analysis the present results allow a first estimation to be given of the error on the absolute MSRDs, simply from the DOS standard deviation of the crystal. Typical values of the DOS standard deviation are of the order of a few THz. As an example, let us consider the case of crystalline germanium, which displays a DOS standard deviation of about 3 THz (Bruesch, 1982). From Figs. 3 and 4, the Einstein fit between 0 and 500 K overestimates MSRD_{\parallel} by about 2% at 300 K, and MSRD_{\perp} by about 3%. In the case of the Einstein fit performed between 0 and 300 K, the error increases by about 1.5 times (as evident by Fig. 5), and the overestimation on MSRD_{\parallel} and MSRD_{\perp} increases by about 3% and 5%, respectively. Accordingly, the resulting EXAFS MSRDs should be properly corrected to improve their accuracy.

4. Einstein model and crystal dynamics

Before the conclusion, let us make a final consideration on the Einstein model and on the corresponding crystal dynamics.

Let us indicate by $\gamma(T)$ the ratio

$$\gamma(T) = \text{MSRD}_{\perp}(T) / \text{MSRD}_{\parallel}(T), \quad (13)$$

which measures the anisotropy of relative thermal vibrations. If $\text{MSRD}_{\parallel}(T)$ and $\text{MSRD}_{\perp}(T)$ can be described by a correlated Einstein model, then by inserting equations (3) and (4) into equation (13) one obtains

$$\gamma(T \rightarrow 0) = 2\nu_{\parallel} / \nu_{\perp}, \quad (14)$$

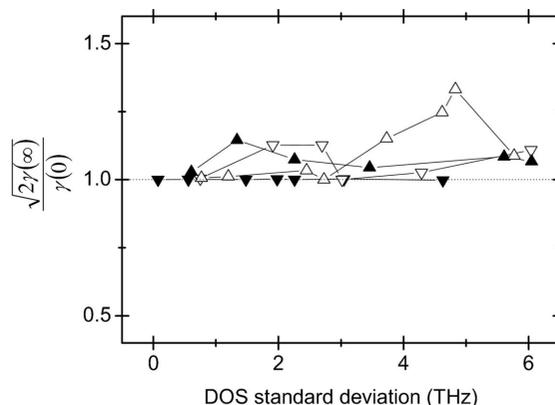
and

$$\gamma(T \rightarrow +\infty) = 2\nu_{\parallel}^2 / \nu_{\perp}^2, \quad (15)$$

and, by comparing the last two equations,

$$\gamma(T \rightarrow 0) = [2\gamma(T \rightarrow +\infty)]^{1/2}. \quad (16)$$

As a result, in the correlated Einstein model the temperature dependence of $\gamma(T)$ follows the condition expressed by equation (16). This is the case, for example, of perfect isotropy, where $\gamma(T) = 2$ at all temperatures.


Figure 7

Calculated ratio $[2\gamma(T \rightarrow +\infty)]^{1/2} / \gamma(T \rightarrow 0)$. Symbols are the same as in Fig. 3.

Fig. 7 shows the ratio $[2\gamma(T \rightarrow +\infty)]^{1/2}/\gamma(T \rightarrow 0)$ calculated in the 27 crystals of this work [with $\gamma(T \rightarrow +\infty)$ approximated to γ at 1000 K]: in most cases this ratio is closer to unity. However, this does not mean that the Einstein model works well: equation (16) is a necessary but not sufficient condition of the crystal dynamics to describe $\text{MSRD}_{\parallel}(T)$ and $\text{MSRD}_{\perp}(T)$ by the correlated Einstein model.

5. Conclusions

In this work the error owing to the Einstein fit on the absolute value of EXAFS MSRDS has been estimated by means of dynamical simulations. On average the error is less than $\sim 5\%$ for the parallel MSRDS, less than 10% for the perpendicular MSRDS, but it should be taken into account to improve the MSRDS accuracy. The fitting error depends on the fitting range and, in principle, decreases neglecting the low temperatures. Finally, in the fitting of perpendicular MSRDS, the importance of equation (6) has been demonstrated.

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